THERMAL CHARACTERISTICS

| Symbol | Parameter | Ratings | Unit |
|-----------------|--|---------|------|
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient (Note 1) | 415 | °C/W |

 R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θCA} is determined by the user's board design. R_{θJA} = 415°C/W on minimum pad mounting on FR-4 board in still air.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | | |
|--------------------------------|--|--|-----|-----|-----|-------|--|--|
| OFF CHARACTERISTICS | | | | | | | | |
| BV _{DSS} | Drain-Source Breakdown Voltage | V_{GS} = 0 V, I _D = 250 µA | 25 | - | - | V | | |
| $\Delta BV_{DSS} / \Delta T_J$ | Breakdown Voltage Temperature Coefficient | $I_D = 250 \ \mu\text{A}$, Referenced to 25°C | - | 25 | - | mV/°C | | |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 20 V, V _{GS} = 0 V | - | - | 1 | μA | | |
| | | V_{DS} = 20 V, V_{GS} = 0 V, T_J = 55 $^\circ C$ | - | - | 10 | μA | | |
| I _{GSS} | Gate-Body Leakage Current | $V_{GS} = 8 V, V_{DS} = 0 V$ | - | - | 100 | nA | | |
| ON CHARACTERISTICS (Note 2) | | | | | | | | |

0.65 V Gate Threshold Voltage $V_{DS}=V_{GS},\,I_{D}=250\;\mu A$ 0.85 1.5 V_{GS(th)} Gate Threshold Voltage $I_D = 250 \ \mu$ A, Referenced to 25° C -2.1 mV/°C $\Delta V_{GS(th)} / \Delta T_J$ _ _ Temperature Coefficient Static Drain-Source V_{GS} = 4.5 V, I_D = 0.22 A 4 R_{DS(on)} _ 2.6 Ω **On-Resistance** V_{GS} = 4.5 V, I_D = 0.22 A, T_J = 125°C 5.3 7 _ $V_{GS} = 2.7 \text{ V}, I_D = 0.19 \text{ A}$ 3.7 5 _ **On-State Drain Current** $V_{GS} = 4.5 V, V_{DS} = 5 V$ 0.22 А I_{D(on)} _ - $V_{DS} = 5 \text{ V}, I_{D} = 0.22 \text{ A}$ S Forward Transconductance 0.2 **g**fs _

DYNAMIC CHARACTERISTICS

| C _{iss} | Input Capacitance | V_{DS} = 10 V, V_{GS} = 0 V, f = 1.0 MHz | _ | 9.5 | - | pF |
|------------------|------------------------------|--|---|-----|---|----|
| C _{oss} | Output Capacitance | | - | 6 | - | pF |
| C _{rss} | Reverse Transfer Capacitance | | - | 4.5 | - | pF |

SWITCHING CHARACTERISTICS (Note 2)

| t _{D(on)} | Turn-On Delay Time | $V_{DD} = 5 V, I_D = 0.5 A,$ | - | 5 | 10 | ns |
|---------------------|---------------------|---|---|------|-----|----|
| t _r | Turn-On Rise Time | $V_{\rm GS}$ = 4.5 V, $R_{\rm GEN}$ = 50 Ω | - | 4.5 | 10 | ns |
| t _{D(off)} | Turn-Off Delay Time | | - | 4 | 8 | ns |
| t _f | Turn-Off Fall Time | | - | 3.2 | 7 | ns |
| Qg | Total Gate Charge | $V_{DS} = 5 V, I_D = 0.22 A,$ $V_{GS} = 4.5 V$ | - | 0.29 | 0.4 | nC |
| Q _{gs} | Gate-Source Charge | $v_{GS} = 4.5 v$ | - | 0.12 | - | nC |
| Q _{gd} | Gate-Drain Charge | | - | 0.03 | - | nC |

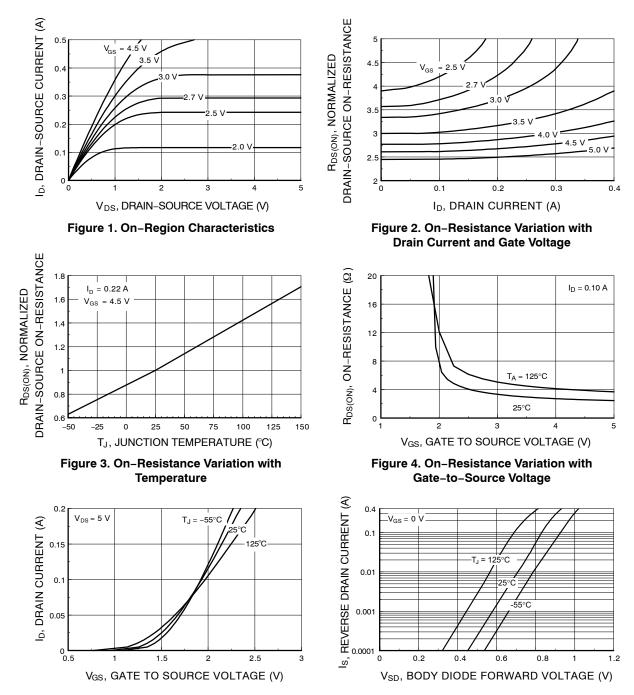
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS

| I _S | Maximum Continuous Source Current | | - | - | 0.25 | А |
|-----------------|---------------------------------------|--|---|-----|------|---|
| V _{SD} | Drain-Source Diode Forward Voltage | V_{GS} = 0 V, I _S = 0.25 A (Note 2) | - | 0.8 | 1.2 | V |

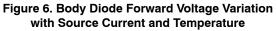
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

TYPICAL PERFORMANCE CHARACTERISTICS







TYPICAL PERFORMANCE CHARACTERISTICS (continued)

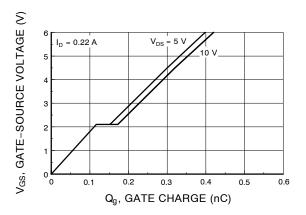


Figure 7. Gate Charge Characteristics

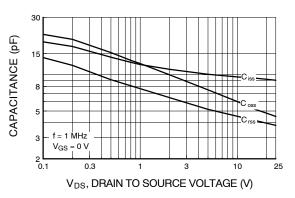


Figure 8. Capacitance Characteristics

SINGLE PULSE

 $R_{\theta JA} = 415^{\circ}C/W$

10

200

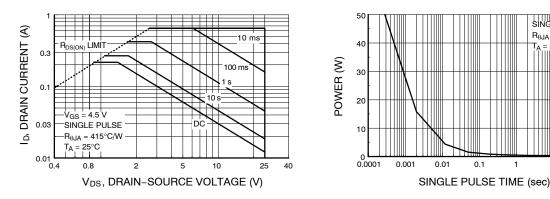
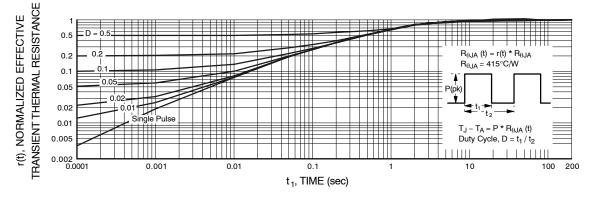


Figure 9. Maximum Safe Operating Area

Figure 10. Single Pulse Maximum Power Dissipation

0.1



Thermal characterization performed using the conditions described in Note 1. Transient thermal response will change depending on the circuit board design.

Figure 11. Transient Thermal Response Curve

ORDERING INFORMATION

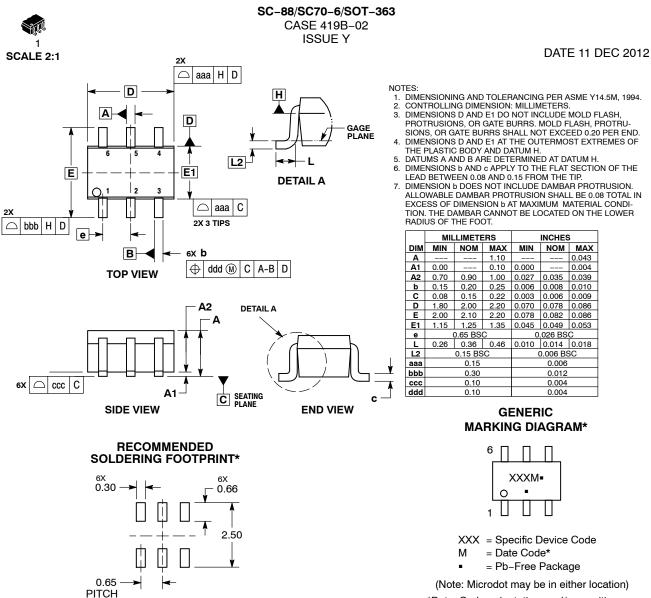
| Device Order Number | Device Marking | Package Type | Shipping [†] |
|---------------------|----------------|-----------------------------------|-----------------------|
| FDG6301N | 01 | SC-88/SC70-6/SOT-363 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

0.043

0.004





DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

| STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2 | STYLE 2: CANCELLED | STYLE 3: CANCELLED | STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE | STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE | STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2 |
|--|-----------------------|--|---|---|---|
| STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2 | STYLE 8: CANCELLED | STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2 | STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2 | STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2 | STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2 |
| STYLE 13: | STYLE 14: | STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: |
| PIN 1. ANODE | PIN 1. VREF | PIN 1. ANODE 1 | PIN 1. BASE 1 | PIN 1. BASE 1 | PIN 1. VIN1 |
| 2. N/C | 2. GND | 2. ANODE 2 | 2. EMITTER 2 | 2. EMITTER 1 | 2. VCC |
| 3. COLLECTOR | 3. GND | 3. ANODE 3 | 3. COLLECTOR 2 | 3. COLLECTOR 2 | 3. VOUT2 |
| 4. EMITTER | 4. IOUT | 4. CATHODE 3 | 4. BASE 2 | 4. BASE 2 | 4. VIN2 |
| 5. BASE | 5. VEN | 5. CATHODE 2 | 5. EMITTER 1 | 5. EMITTER 2 | 5. GND |
| 6. CATHODE | 6. VCC | 6. CATHODE 1 | 6. COLLECTOR 1 | 6. COLLECTOR 1 | 6. VOUT1 |
| STYLE 19: | STYLE 20: | STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: |
| PIN 1. I OUT | PIN 1. COLLECTOR | PIN 1. ANODE 1 | PIN 1. D1 (i) | PIN 1. Vn | PIN 1. CATHODE |
| 2. GND | 2. COLLECTOR | 2. N/C | 2. GND | 2. CH1 | 2. ANODE |
| 3. GND | 3. BASE | 3. ANODE 2 | 3. D2 (i) | 3. Vp | 3. CATHODE |
| 4. V CC | 4. EMITTER | 4. CATHODE 2 | 4. D2 (c) | 4. N/C | 4. CATHODE |
| 5. V EN | 5. COLLECTOR | 5. N/C | 5. VBUS | 5. CH2 | 5. CATHODE |
| 6. V REF | 6. COLLECTOR | 6. CATHODE 1 | 6. D1 (c) | 6. N/C | 6. CATHODE |
| STYLE 25: | STYLE 26: | STYLE 27: | STYLE 28: | STYLE 29: | STYLE 30: |
| PIN 1. BASE 1 | PIN 1. SOURCE 1 | PIN 1. BASE 2 | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. SOURCE 1 |
| 2. CATHODE | 2. GATE 1 | 2. BASE 1 | 2. DRAIN | 2. ANODE | 2. DRAIN 2 |
| 3. COLLECTOR 2 | 3. DRAIN 2 | 3. COLLECTOR 1 | 3. GATE | 3. COLLECTOR | 3. DRAIN 2 |
| 4. BASE 2 | 4. SOURCE 2 | 4. EMITTER 1 | 4. SOURCE | 4. EMITTER | 4. SOURCE 2 |
| 5. EMITTER | 5. GATE 2 | 5. EMITTER 2 | 5. DRAIN | 5. BASE/ANODE | 5. GATE 1 |
| 6. COLLECTOR 1 | 6. DRAIN 1 | 6. COLLECTOR 2 | 6. DRAIN | 6. CATHODE | 6. DRAIN 1 |

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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